## Operational Amplifier, Rail-to-Rail Output, $\mathbf{3} \mathbf{~ M H z}$ BW

## TLV271, TLV272, NCV272, TLV274, NCV274

The TLV/NCV27x operational amplifiers provide rail-to-rail output operation. The output can swing within 320 mV to the positive rail and 50 mV to the negative rail. This rail-to-rail operation enables the user to make optimal use of the entire supply voltage range while taking advantage of 3 MHz bandwidth. The opamp can operate on supply voltage as low as 2.7 V over the temperature range of $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$. The high bandwidth provides a slew rate of $2.4 \mathrm{~V} / \mu \mathrm{s}$ while only consuming $550 \mu \mathrm{~A}$ of quiescent current. Likewise the opamp can run on a supply voltage as high as 16 V (single) and 36 V (dual quad) making it ideal for a broad range of battery-operated applications. Since this is a CMOS device it has high input impedance and low bias currents making it ideal for interfacing to a wide variety of signal sensors. In addition it comes in a variety of compact packages with different pinout styles allowing for use in high-density PCB's.

## Features

- Rail-To-Rail Output
- Wide Bandwidth: 3 MHz
- High Slew Rate: 2.4 V/us
- Wide Power-Supply Range: 2.7 V to 16 V (TLV271),

36 V (TLV/NCV272/274)

- Low Supply Current: $550 \mu \mathrm{~A}$
- Low Input Bias Current: 45 pA
- Wide Temperature Range: $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
- TSOP-5, Micro-8, SOIC-8, SOIC-14, TSSOP-14 Packages
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are $\mathrm{Pb}-$ Free, Halogen Free/BFR Free and are RoHS Compliant


## Applications

- Notebook Computers
- Portable Instruments
- Signal Conditioning
- Automotive
- Power Supplies
- Current Sensing ON Semiconductor ${ }^{\text {® }}$ www.onsemi.com


DEVICE MARKING INFORMATION
See general marking information in the device marking section on page 2 of this data sheet.

## ORDERING INFORMATION

See detailed ordering and shipping information on page 3 of this data sheet.

MARKING DIAGRAMS


## TLV271, TLV272, NCV272, TLV274, NCV274

## PIN CONNECTIONS

## Single Channel Configuration

TLV271


Dual Channel Configuration
TLV272, NCV272
OUT


Quadruple Channel Configuration
TLV274, NCV274


ORDERING INFORMATION

| Device | Configuration | Automotive | Marking | Package | Shipping ${ }^{\dagger}$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| TLV271SN1T1G (Style 1 Pinout) | Single | No | ADG | TSOP-5 | 3000 / Tape and Reel |
| TLV271SN2T1G (Style 2 Pinout) |  |  | ADH |  | 3000 / Tape and Reel |
| TLV272DR2G |  |  | V272 | SOIC-8 | 2500 / Tape and Reel |
| TLV272DMR2G |  |  | V272 | Micro-8/MSOP-8 | 4000 / Tape and Reel |
| TLV274DR2G |  |  | V274 | SOIC-14 | 2500 / Tape and Reel |
| TLV274DTBR2G |  |  | V274 | TSSOP-14 | 2500 / Tape and Reel |
| NCV272DR2G* |  | Yes | V272 | SOIC-8 | 2500 / Tape and Reel |
| NCV272DMR2G* | Dual |  | V272 | Micro-8/MSOP-8 | 4000 / Tape and Reel |
| NCV274DR2G* | Quad |  | V274 | SOIC-14 | 2500 / Tape and Reel |
| NCV274DTBR2G* |  |  | V274 | TSSOP-14 | 2500 / Tape and Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

MAXIMUM RATINGS

| Symbol | Rating |  | Value | Unit |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{DD}}$ | Supply Voltage (Note 1) | $\begin{array}{r} \text { TLV271 } \\ \text { TLV/NCV272/274 } \end{array}$ | $\begin{gathered} 16.5 \\ 36 \end{gathered}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{\text {ID }}$ | Input Differential Voltage |  | $\pm$ Supply Voltage | V |
| $\mathrm{V}_{1}$ | Input Common Mode Voltage Range (Note 1) |  | $\begin{gathered} -0.2 \mathrm{~V} \text { to }\left(\mathrm{V}_{\mathrm{DD}}+\right. \\ 0.2 \mathrm{~V}) \end{gathered}$ | V |
| 1 | Maximum Input Current |  | $\pm 10$ | mA |
| 10 | Output Current Range |  | $\pm 100$ | mA |
|  | Continuous Total Power Dissipation (Note 1) |  | 200 | mW |
| $\mathrm{T}_{J}$ | Maximum Junction Temperature |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {A }}$ | Operating Ambient Temperature Range (free-air) |  | -40 to 125 | ${ }^{\circ} \mathrm{C}$ |
| TSTG | Storage Temperature Range |  | -65 to 150 | ${ }^{\circ} \mathrm{C}$ |
| ESD ${ }_{\text {HBM }}$ | ESD Capability, Human Body Model |  | 2 | kV |
| ESD ${ }_{\text {CDM }}$ | ESD Capability, Charged Device Model | TLV271 <br> TLV/NCV272 <br> TLV/NCV274 | $\begin{gathered} \hline \text { TBD } \\ 2 \\ 1 \end{gathered}$ | $\begin{aligned} & \mathrm{kV} \\ & \mathrm{kV} \\ & \mathrm{kV} \end{aligned}$ |
|  | Mounting Temperature (Infrared or Convection - 20 sec ) |  | 260 | ${ }^{\circ} \mathrm{C}$ |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Continuous short-circuit operation to ground at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of $150^{\circ} \mathrm{C}$. Output currents in excess of 45 mA over long term may adversely affect reliability. Shorting output to either V+ or V - will adversely affect reliability.

THERMAL INFORMATION

| Parameter | Symbol | Package | Single Layer Board (Note 2) | Multi-Layer <br> Board (Note 3) | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Junction-to-Ambient | $\theta_{\text {JA }}$ | TSOP-5 | 333 | 195 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
|  |  | Micro-8 / MSOP-8 | 236 | 167 |  |
|  |  | SOIC-8 | 190 | 131 |  |
|  |  | SOIC-14 | 142 | 101 |  |
|  |  | TSSOP-14 | 179 | 128 |  |

2. Values based on a 1 S standard PCB according to JEDEC51-3 with 1.0 oz copper and a $300 \mathrm{~mm}^{2}$ copper area
3. Values based on a 1S2P standard PCB according to JEDEC51-7 with 1.0 oz copper and a $100 \mathrm{~mm}^{2}$ copper area

TLV271 DC ELECTRICAL CHARACTERISTICS
$\left(\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}, 3.3 \mathrm{~V}, 5 \mathrm{~V} \& \pm 5 \mathrm{~V}\right.$ (Note 4), $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}} \geq 10 \mathrm{k} \Omega$ unless otherwise noted)

| Parameter | Symbol | Conditions |  | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input Offset Voltage | $\mathrm{V}_{10}$ | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{~V}_{\mathrm{O}}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega, \mathrm{R}_{\mathrm{S}}=50 \Omega$ |  |  | 0.5 | 5 | mV |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  |  |  | 7 |  |
| Offset Voltage Drift | $\mathrm{ICV}_{\text {OS }}$ | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{~V}_{\mathrm{O}}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega, \mathrm{R}_{\mathrm{S}}=50 \Omega$ |  |  | 2 |  | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| Common Mode Rejection Ratio | CMRR | $0 \mathrm{~V} \leq \mathrm{VIC} \leq \mathrm{V}_{\mathrm{DD}}-1.35 \mathrm{~V}, \mathrm{R}_{\mathrm{S}}=50 \Omega$ | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ | 58 | 70 |  | dB |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 55 |  |  |  |
|  |  | $0 \mathrm{~V} \leq \mathrm{VIC} \leq \mathrm{V}_{\mathrm{DD}}-1.35 \mathrm{~V}, \mathrm{R}_{\mathrm{S}}=50 \Omega$ | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ | 65 | 130 |  |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 62 |  |  |  |
|  |  | $0 \mathrm{~V} \leq \mathrm{VIC} \leq \mathrm{V}_{\mathrm{DD}}-1.35 \mathrm{~V}, \mathrm{R}_{\mathrm{S}}=50 \Omega$ | $\mathrm{V}_{\mathrm{DD}}= \pm 5 \mathrm{~V}$ | 69 | 140 |  |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 66 |  |  |  |
| Power Supply Rejection Ratio | PSRR | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ to 16 V , VIC $=\mathrm{V}_{\mathrm{DD}} / 2$, No Load |  | 70 | 135 |  | dB |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 65 |  |  |  |
| Large Signal Voltage Gain | $A_{V D}$ | $\mathrm{V}_{\mathrm{O}(\mathrm{pp})}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ | 97 | 106 |  | dB |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 76 |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{O}(\mathrm{pp})}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ | $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}$ | 97 | 123 |  |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 76 |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{O}(\mathrm{pp})}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ | 100 | 127 |  |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 86 |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{O}(\mathrm{pp})}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ | $\mathrm{V}_{\mathrm{DD}}= \pm 5 \mathrm{~V}$ | 100 | 130 |  |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 90 |  |  |  |
| Input Bias Current | $\mathrm{I}_{\mathrm{B}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{~V}_{\mathrm{O}}=\mathrm{V}_{\mathrm{DD}} / 2, \\ & \mathrm{R}_{\mathrm{S}}=50 \Omega \end{aligned}$ | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 45 | 150 | pA |
|  |  |  | $\mathrm{T}_{\mathrm{A}}=105^{\circ} \mathrm{C}$ |  |  | 1000 |  |
| Input Offset Current | $\mathrm{I}_{10}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{~V}_{\mathrm{O}}=\mathrm{V}_{\mathrm{DD}} / 2, \\ & \mathrm{R}_{\mathrm{S}}=50 \Omega \end{aligned}$ | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 45 | 150 | pA |
|  |  |  | $\mathrm{T}_{\mathrm{A}}=105^{\circ} \mathrm{C}$ |  |  | 1000 |  |
| Differential Input Resistance | $\mathrm{r}_{\mathrm{i}}(\mathrm{d})$ |  |  |  | 1000 |  | G $\Omega$ |
| Common-mode Input Capacitance | $\mathrm{C}_{\text {IC }}$ | $\mathrm{f}=21 \mathrm{kHz}$ |  |  | 8 |  | pF |

4. $V_{D D}= \pm 5 \mathrm{~V}$ is shorthand for $\mathrm{V}_{\mathrm{DD}}=+5 \mathrm{~V}$ and $\mathrm{V}_{\mathrm{EE}}=-5 \mathrm{~V}$.

TLV271 DC ELECTRICAL CHARACTERISTICS
( $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}, 3.3 \mathrm{~V}, 5 \mathrm{~V} \& \pm 5 \mathrm{~V}$ (Note 4), $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}} \geq 10 \mathrm{k} \Omega$ unless otherwise noted)

| Parameter | Symbol | Conditions |  | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Output Swing <br> (High-level) | $\mathrm{V}_{\mathrm{OH}}$ | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{I}_{\mathrm{OH}}=-1 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ | 2.55 | 2.58 |  | V |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 2.48 |  |  |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{I}_{\mathrm{OH}}=-1 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}$ | 3.15 | 3.21 |  |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 3.00 |  |  |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{I}_{\mathrm{OH}}=-1 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ | 4.8 | 4.93 |  |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 4.75 |  |  |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{I}_{\mathrm{OH}}=-1 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{DD}}= \pm 5 \mathrm{~V}$ | 4.92 | 4.96 |  |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 4.9 |  |  |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{I}_{\mathrm{OH}}=-5 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ | 1.9 | 2.1 |  | V |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 1.5 |  |  |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{I}_{\mathrm{OH}}=-5 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}$ | 2.5 | 2.89 |  |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 2.1 |  |  |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{I}_{\mathrm{OH}}=-5 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ | 4.5 | 4.68 |  |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 4.35 |  |  |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{I}_{\mathrm{OH}}=-5 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{DD}}= \pm 5 \mathrm{~V}$ | 4.7 | 4.78 |  |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 4.65 |  |  |  |
| Output Swing (Low-level) | VoL | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{I}_{\mathrm{OL}}=-1 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ |  | 0.1 | 0.15 | V |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  |  |  | 0.22 |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{I}_{\mathrm{OL}}=-1 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}$ |  | 0.03 | 0.15 |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  |  |  | 0.22 |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{I}_{\mathrm{OL}}=-1 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 0.03 | 0.1 |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  |  |  | 0.15 |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{I}_{\mathrm{OL}}=-1 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{DD}}= \pm 5 \mathrm{~V}$ |  | 0.05 | 0.08 |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  |  |  | 0.1 |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{I}_{\mathrm{OL}}=-5 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ |  | 0.5 | 0.7 | V |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  |  |  | 1.1 |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{I}_{\mathrm{OL}}=-5 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}$ |  | 0.13 | 0.7 |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  |  |  | 1.1 |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{I}_{\mathrm{OL}}=-5 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 0.13 | 0.4 |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  |  |  | 0.5 |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{I}_{\mathrm{OL}}=-5 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{DD}}= \pm 5 \mathrm{~V}$ |  | 0.16 | 0.3 |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  |  |  | 0.35 |  |
| Output Current | Io | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ from rail, $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ | Positive rail |  | 4.0 |  | mA |
|  |  |  | Negative rail |  | 5.0 |  |  |
|  |  | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ from rail, $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ | Positive rail |  | 7.0 |  |  |
|  |  |  | Negative rail |  | 8.0 |  |  |
|  |  | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ from rail, $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$ | Positive rail |  | 13 |  |  |
|  |  |  | Negative rail |  | 12 |  |  |

4. $\mathrm{V}_{\mathrm{DD}}= \pm 5 \mathrm{~V}$ is shorthand for $\mathrm{V}_{\mathrm{DD}}=+5 \mathrm{~V}$ and $\mathrm{V}_{\mathrm{EE}}=-5 \mathrm{~V}$.

TLV271 DC ELECTRICAL CHARACTERISTICS
$\left(\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}, 3.3 \mathrm{~V}, 5 \mathrm{~V} \& \pm 5 \mathrm{~V}\right.$ (Note 4), $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}} \geq 10 \mathrm{k} \Omega$ unless otherwise noted)

| Parameter | Symbol | Conditions |  | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Power Supply Quiescent Current | IDD | $\mathrm{V}_{\mathrm{O}}=\mathrm{V}_{\mathrm{DD}} / 2$ | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ |  | 380 | 560 | $\mu \mathrm{A}$ |
|  |  |  | $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}$ |  | 385 | 620 |  |
|  |  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 390 | 660 |  |
|  |  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$ |  | 400 | 800 |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  |  |  | 1000 |  |

4. $\mathrm{V}_{\mathrm{DD}}= \pm 5 \mathrm{~V}$ is shorthand for $\mathrm{V}_{\mathrm{DD}}=+5 \mathrm{~V}$ and $\mathrm{V}_{\mathrm{EE}}=-5 \mathrm{~V}$.

TLV271 AC ELECTRICAL CHARACTERISTICS
$\left(\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}, 5 \mathrm{~V}, \& \pm 5 \mathrm{~V}\right.$ (Note 5), $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, and $\mathrm{R}_{\mathrm{L}} \geq 10 \mathrm{k} \Omega$ unless otherwise noted)

| Parameter | Symbol | Conditions |  | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Unity Gain Bandwidth | UGBW | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=10 \mathrm{pF}$ | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ |  | 3.2 |  | MHz |
|  |  |  | $\begin{gathered} \mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V} \text { to } \\ 10 \mathrm{~V} \end{gathered}$ |  | 3.5 |  |  |
| Slew Rate at Unity Gain | SR | $\mathrm{V}_{\mathrm{O}(\mathrm{pp})}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ | 1.35 | 2.1 |  | V/uS |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 1 |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{O}(\mathrm{pp})}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ | 1.45 | 2.3 |  |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 1.2 |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{O}(\mathrm{pp})}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ | $\mathrm{V}_{\mathrm{DD}}= \pm 5 \mathrm{~V}$ | 1.8 | 2.6 |  |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  | 1.3 |  |  |  |
| Phase Margin | $\theta_{\mathrm{m}}$ | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=10 \mathrm{pF}$ |  |  | 45 |  | - |
| Gain Margin |  | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=10 \mathrm{pF}$ |  |  | 14 |  | dB |
| Settling Time to$0.1 \%$ | $\mathrm{t}_{\mathrm{s}}$ | $\begin{aligned} & \mathrm{V} \text {-step }(\mathrm{pp})=1 \mathrm{~V}, \mathrm{AV}=-1, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega, \\ & \mathrm{C}_{\mathrm{L}}=10 \mathrm{pF} \end{aligned}$ | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ |  | 2.9 |  | $\mu \mathrm{S}$ |
|  |  | $\begin{aligned} & \mathrm{V} \text {-step }(\mathrm{pp})=1 \mathrm{~V}, \mathrm{AV}=-1, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega, \\ & \mathrm{C}_{\mathrm{L}}=47 \mathrm{pF} \end{aligned}$ | $\begin{gathered} \mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \\ \pm 5 \mathrm{~V} \end{gathered}$ |  | 2.0 |  |  |
| Total Harmonic Distortion plus Noise | THD+N | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}(\mathrm{pp})}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega, \\ & \mathrm{f}=10 \mathrm{kHz} \end{aligned}$ | $\mathrm{AV}=1$ |  | 0.004 |  | \% |
|  |  |  | $A V=10$ |  | 0.04 |  |  |
|  |  |  | AV $=100$ |  | 0.3 |  |  |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \pm 5 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}(\mathrm{pp})}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{R}_{\mathrm{L}}= \\ & 2 \mathrm{k} \Omega, \mathrm{f}=10 \mathrm{kHz} \end{aligned}$ | $\mathrm{AV}=1$ |  | 0.004 |  |  |
|  |  |  | $A V=10$ |  | 0.04 |  |  |
|  |  |  | AV $=100$ |  | 0.03 |  |  |
| Input-Referred Voltage Noise | $e_{n}$ | $\mathrm{f}=1 \mathrm{kHz}$ |  |  | 30 |  | $\mathrm{nV} / \sqrt{\mathrm{Hz}}$ |
|  |  | $\mathrm{f}=10 \mathrm{kHz}$ |  |  | 20 |  |  |
| Input-Referred Current Noise | $\mathrm{i}_{\mathrm{n}}$ | $\mathrm{f}=1 \mathrm{kHz}$ |  |  | 0.6 |  | $\mathrm{fA} / \sqrt{\mathrm{Hz}}$ |

5. $\mathrm{V}_{\mathrm{DD}}= \pm 5 \mathrm{~V}$ is shorthand for $\mathrm{V}_{\mathrm{DD}}=+5 \mathrm{~V}$ and $\mathrm{V}_{\mathrm{EE}}=-5 \mathrm{~V}$.

TLV/NCV 272/274 DC ELECTRICAL CHARACTERISTICS
( $\left(\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}, 5 \mathrm{~V}, 10 \mathrm{~V}, 36 \mathrm{~V}\right), \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}} \geq 10 \mathrm{k} \Omega$ unless otherwise noted)

| Parameter | Symbol | Conditions |  | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input Offset Voltage | $\mathrm{V}_{10}$ | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{~V}_{\mathrm{O}}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ |  |  | 1.3 | $\pm 3$ | mV |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  |  |  | $\pm 4$ |  |
| Offset Voltage Drift | $\mathrm{ICV}_{\text {OS }}$ | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{~V}_{\mathrm{O}}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ |  |  | 2 |  | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| Common Mode Rejection Ratio | CMRR | $\mathrm{V}_{\mathrm{CM}}=\mathrm{V}_{\text {SS }}+0.2 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{DD}}-1.35 \mathrm{~V}$ | $V_{D D}=2.7 \mathrm{~V}$ | 90 | 110 |  | dB |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  | 69 |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CM}}=\mathrm{V}_{\text {SS }}+0.2 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{DD}}-1.35 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ | 102 | 125 |  |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  | 80 |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CM}}=\mathrm{V}_{\text {SS }}+0.2 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{DD}}-1.35 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$ | 110 | 130 |  |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  | 87 |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CM}}=\mathrm{V}_{\text {SS }}+0.2 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{DD}}-1.35 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{DD}}=36 \mathrm{~V}$ | 120 | 145 |  |  |
|  |  | $\begin{array}{ll} \hline \mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C} \begin{array}{l} (\mathrm{TLV} / \mathrm{NCV} 272) \\ (\mathrm{TLV} / \mathrm{NCV} 274) \end{array} \end{array}$ |  | $\begin{aligned} & 95 \\ & 85 \end{aligned}$ |  |  |  |
| Power Supply Rejection Ratio | PSRR | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ to $36 \mathrm{~V}, \mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2$, No Load |  | 114 | 135 |  | dB |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  | 100 |  |  |  |
| Large Signal Voltage Gain | AvD | $\mathrm{V}_{\mathrm{O}(\mathrm{pp})}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ | 96 | 118 |  | dB |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  | 86 |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{O}(\mathrm{pp})}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ | 96 | 120 |  |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  | 86 |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{O}(\mathrm{pp})}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ | $V_{D D}=10 \mathrm{~V}$ | 98 | 120 |  |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  | 88 |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{O}(\mathrm{pp})}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ | $\mathrm{V}_{\mathrm{DD}}=36 \mathrm{~V}$ | 98 | 120 |  |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  | 88 |  |  |  |
| Input Bias Current | $\mathrm{I}_{\mathrm{B}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=2.7 \text { to } 36 \mathrm{~V}, \\ & \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C} \end{aligned}$ | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 5 | 200 | pA |
|  |  |  | TLV/NCV272 |  |  | 2000 |  |
|  |  |  | TLV/NCV274 |  |  | 1500 |  |
| Input Offset Current | $\mathrm{I}_{10}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2, \mathrm{~V}_{\mathrm{O}}=\mathrm{V}_{\mathrm{DD}} / 2, \\ & \mathrm{R}_{\mathrm{S}}=50 \Omega \end{aligned}$ | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 2 | 75 | pA |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=2.7 \text { to } 36 \mathrm{~V}, \\ & \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C} \end{aligned}$ | TLV/NCV272 |  |  | 500 |  |
|  |  |  | TLV/NCV274 |  |  | 200 |  |
| Channel Separation | XTLK | DC | TLV/NCV272 |  | 100 |  | dB |
|  |  |  | TLV/NCV274 |  | 115 |  | dB |
| Differential Input Resistance | $\mathrm{R}_{\mathrm{i}(\mathrm{d})}$ |  |  |  | 5 |  | $\mathrm{G} \Omega$ |
| Common-mode Input Capacitance | $\mathrm{ClC}_{\text {I }}$ |  |  |  | 3.5 |  | pF |

TLV/NCV 272/274 DC ELECTRICAL CHARACTERISTICS
( $\left(\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}, 5 \mathrm{~V}, 10 \mathrm{~V}, 36 \mathrm{~V}\right), \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}} \geq 10 \mathrm{k} \Omega$ unless otherwise noted)

| Parameter | Symbol | Conditions |  | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Output Swing (High-level) | $\mathrm{V}_{\mathrm{OH}}$ | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2$ | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ |  | 0.006 | 0.15 | V |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  |  |  | 0.22 |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2$ | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 0.013 | 0.20 |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  |  |  | 0.25 |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2$ | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$ |  | 0.023 | 0.08 |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  |  |  | 0.10 |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2$ | $\mathrm{V}_{\mathrm{DD}}=36 \mathrm{~V}$ |  | 0.074 | 0.10 |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  |  |  | 0.15 |  |
| Output Swing (Low-level) | $\mathrm{V}_{\text {OL }}$ | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2$ | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ |  | 0.005 | 0.15 | V |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  |  |  | 0.22 |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2$ | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 0.01 | 0.10 |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  |  |  | 0.15 |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2$ | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$ |  | 0.022 | 0.3 |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  |  |  | 0.35 |  |
|  |  | $\mathrm{VIC}=\mathrm{V}_{\mathrm{DD}} / 2$ | $\mathrm{V}_{\mathrm{DD}}=36 \mathrm{~V}$ |  | 0.065 | 0.3 |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  |  |  | 0.35 |  |
| Output Current | 10 | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ | Positive rail |  | 50 |  | mA |
|  |  |  | Negative rail |  | 70 |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ | Positive rail |  | 60 |  |  |
|  |  |  | Negative rail |  | 50 |  |  |
|  |  | $V_{D D}=10 \mathrm{~V}$ | Positive rail |  | 65 |  |  |
|  |  |  | Negative rail |  | 50 |  |  |
|  |  | $\mathrm{V}_{\mathrm{DD}}=36 \mathrm{~V}$ | Positive rail |  | 65 |  |  |
|  |  |  | Negative rail |  | 50 |  |  |
| Power Supply Quiescent Current | $\mathrm{I}_{\mathrm{DD}}$ | $\mathrm{V}_{\mathrm{O}}=\mathrm{V}_{\mathrm{DD}} / 2,$ <br> Per channel, no load | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ |  | 405 | 525 | $\mu \mathrm{A}$ |
|  |  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 410 | 530 |  |
|  |  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$ |  | 416 | 540 |  |
|  |  |  | $\mathrm{V}_{\mathrm{DD}}=36 \mathrm{~V}$ |  | 465 | 600 |  |
|  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |  |  |  | 700 |  |

NOTE: Power dissipation must be limited to prevent junction temperature from exceeding $150^{\circ} \mathrm{C}$. See Absolute Maximum Ratings for more information.

## TLV271, TLV272, NCV272, TLV274, NCV274

TLV/NCV 272/274 AC ELECTRICAL CHARACTERISTICS
$\left(\left(\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}, 5 \mathrm{~V}, 10 \mathrm{~V}, 36 \mathrm{~V}\right), \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$, and $\mathrm{R}_{\mathrm{L}} \geq 10 \mathrm{k} \Omega$ unless otherwise noted)

| Parameter | Symbol | Conditions |  | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Unity Gain Bandwidth | UGBW | $\mathrm{C}_{\mathrm{L}}=25 \mathrm{pF}$ | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ |  | 3 |  | MHz |
| Slew Rate at Unity Gain | SR | $\mathrm{C}_{\mathrm{L}}=20 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ |  | 2.8 |  | V/uS |
|  |  |  | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 2.7 |  |  |
|  |  |  | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$ |  | 2.6 |  |  |
|  |  |  | $V_{D D}=36 \mathrm{~V}$ |  | 2.4 |  |  |
| Phase Margin | $\theta_{\mathrm{m}}$ | $\mathrm{C}_{\mathrm{L}}=25 \mathrm{pF}$ |  |  | 50 |  | 。 |
| Gain Margin |  | $\mathrm{C}_{\mathrm{L}}=25 \mathrm{pF}$ |  |  | 14 |  | dB |
| Settling Time to 0.1\% | ts | $\mathrm{V}_{\mathrm{O}}=1 \mathrm{~V}_{\mathrm{pp}}$, Gain = 1, $\mathrm{C}_{\mathrm{L}}=20 \mathrm{pF}$ | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ |  | 0.6 |  | $\mu \mathrm{S}$ |
|  |  | $\mathrm{V}_{\mathrm{O}}=3 \mathrm{~V}_{\text {pp }}$, Gain $=1, \mathrm{C}_{\mathrm{L}}=20 \mathrm{pF}$ | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 1.2 |  |  |
|  |  | $\mathrm{V}_{\mathrm{O}}=8.5 \mathrm{~V}_{\mathrm{pp}}$, Gain $=1, \mathrm{C}_{\mathrm{L}}=20 \mathrm{pF}$ | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$ |  | 3.4 |  |  |
|  |  | $\mathrm{V}_{\mathrm{O}}=10 \mathrm{~V}_{\mathrm{pp}}$, Gain $=1, \mathrm{C}_{\mathrm{L}}=20 \mathrm{pF}$ | $\mathrm{V}_{\mathrm{DD}}=36 \mathrm{~V}$ |  | 3.2 |  |  |
| Total Harmonic Distortion plus Noise | THD+N | $\mathrm{V}_{\mathrm{IN}}=0.5 \mathrm{~V}_{\mathrm{pp}}, \mathrm{f}=1 \mathrm{kHz}, \mathrm{Av}=1$ | $\mathrm{V}_{\mathrm{DD}}=2.7 \mathrm{~V}$ |  | 0.05 |  | \% |
|  |  | $\mathrm{V}_{\mathrm{IN}}=2.5 \mathrm{~V}_{\mathrm{pp}}, \mathrm{f}=1 \mathrm{kHz}, \mathrm{Av}=1$ | $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ |  | 0.009 |  |  |
|  |  | $\mathrm{V}_{\mathrm{IN}}=7.5 \mathrm{~V}_{\mathrm{pp},}, \mathrm{f}=1 \mathrm{kHz}, \mathrm{Av}=1$ | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$ |  | 0.004 |  |  |
|  |  | $\mathrm{V}_{\mathrm{IN}}=28.5 \mathrm{~V}_{\mathrm{pp}}, \mathrm{f}=1 \mathrm{kHz}, \mathrm{Av}=1$ | $\mathrm{V}_{\mathrm{DD}}=36 \mathrm{~V}$ |  | 0.001 |  |  |
| Input-Referred Voltage Noise | $\mathrm{e}_{\mathrm{n}}$ | $\mathrm{f}=1 \mathrm{kHz}$ |  |  | 30 |  | $\mathrm{nV} / \sqrt{\text { Hz }}$ |
|  |  | $\mathrm{f}=10 \mathrm{kHz}$ |  |  | 20 |  |  |
| Input-Referred Current Noise | $\mathrm{i}_{\mathrm{n}}$ | $\mathrm{f}=1 \mathrm{kHz}$ |  |  | 90 |  | $\mathrm{fA} / \sqrt{ } \mathrm{Hz}$ |

## TLV271, TLV272, NCV272, TLV274, NCV274

TYPICAL CHARACTERISTICS


Figure 1. CMRR vs. Frequency for TLV271


Figure 3. 2.5 V V ${ }_{\text {OL }}$ vs. $\mathrm{I}_{\text {out }}$


Figure 5. 3.3 V Vol vs. Iout


Figure 2. Input Bias and Offset Current vs. Temperature for TLV271


Figure 4. 2.5 V V ${ }_{\mathrm{OH}}$ vs. $\mathrm{I}_{\text {out }}$


Figure 6. 3.3 $\mathrm{V} \mathrm{V}_{\mathrm{OH}}$ vs. $\mathrm{I}_{\text {out }}$

## TLV271, TLV272, NCV272, TLV274, NCV274

TYPICAL CHARACTERISTICS


Figure 7. $\mathrm{V}_{\mathrm{OL}}$ vs. $\mathrm{I}_{\mathrm{out}}$


Figure 9. $10 \mathrm{~V} \mathrm{~V}_{\mathrm{OL}}$ vs. $\mathrm{I}_{\text {out }}$


Figure 11. Peak-to-Peak Output vs. Supply vs. Frequency


Figure 8. $\mathrm{V}_{\mathrm{OH}}$ vs. $\mathrm{I}_{\mathrm{out}}$


Figure 10. $10 \mathrm{~V} \mathrm{~V}_{\mathrm{OH}}$ vs. $\mathrm{I}_{\text {out }}$


Figure 12. Quiescent Current Per Channel vs. Supply Voltage for TLV/NCV272/274

## TLV271, TLV272, NCV272, TLV274, NCV274

TYPICAL CHARACTERISTICS


Figure 13. PSRR vs. Frequency for TLV271


Figure 14. PSRR vs. Frequency for TLV/NCV272/274


Figure 15. Open Loop Gain and Phase vs.
Frequency


Figure 16. Gain Bandwidth Product vs. Temperature


Figure 17. Slew Rate vs. Supply Voltage

## TLV271, TLV272, NCV272, TLV274, NCV274

TYPICAL CHARACTERISTICS


Figure 18. Slew Rate vs. Temperature


Figure 20. 2.5 V Inverting Large Signal Pulse Response


Figure 22. 2.5 V Inverting Small Signal Pulse Response


Figure 19. Voltage Noise vs. Frequency

$500 \mathrm{~ns} /$ div
Figure 21. 2.5 V Non-Inverting Large Signal Pulse Response


Figure 23. 2.5 V Non-Inverting Small Signal Pulse Response

## TLV271, TLV272, NCV272, TLV274, NCV274

TYPICAL CHARACTERISTICS


Figure 24. 3 V Inverting Large Signal Pulse Response


Figure 26. 3 V Inverting Small Signal Pulse Response

$500 \mathrm{~ns} /$ div
Figure 28. 6 V Inverting Large Signal Pulse Response


500 ns/div
Figure 25. 3 V Non-Inverting Large Signal Pulse Response

$500 \mathrm{~ns} / \mathrm{div}$
Figure 27. 3 V Non-Inverting Small Signal Pulse Response

$500 \mathrm{~ns} /$ div
Figure 29. 6 V Non-Inverting Large Signal Pulse Response

## TLV271, TLV272, NCV272, TLV274, NCV274

TYPICAL CHARACTERISTICS


500 ns/div
Figure 30. 6 V Inverting Small Signal Pulse Response


500 ns/div
Figure 31. 6 V Non-Inverting Small Signal Pulse Response

Figure 32. CMRR vs. Frequency for TLV/NCV272/274


Figure 34. Low Level Output vs. Output Current for TLV/NCV272/274



Figure 35. High Level Output vs. Output Current for TLV/NCV272/274

TLV271, TLV272, NCV272, TLV274, NCV274
TYPICAL CHARACTERISTICS


Figure 36. Non-inverting Small Signal Transient Response for TLV/NCV272/274


Figure 38. Non-inverting Large Signal Transient Response for TLV/NCV272/274


Figure 37. Inverting Small Signal Transient Response for TLV/NCV272/274


Figure 39. Inverting Large Signal Transient Response for TLV/NCV272/274

## TLV271, TLV272, NCV272, TLV274, NCV274

## APPLICATIONS



Figure 40. Voltage Reference


Figure 42. Comparator with Hysteresis


Figure 41. Wien Bridge Oscillator

Given: $f_{o}=$ center frequency

$$
A\left(f_{0}\right)=\text { gain at center frequency }
$$

Choose value $\mathrm{f}_{0}, \mathrm{C}_{\mathrm{Q}}$
Then: $R 3=\frac{Q}{\pi f_{O} C}$

$$
\mathrm{R} 1=\frac{\mathrm{R} 3}{2 \mathrm{~A}\left(\mathrm{f}_{\mathrm{O}}\right)}
$$

$$
R 2=\frac{R 1 R 3}{4 Q^{2} R 1-R 3}
$$

For less than $10 \%$ error from operational amplifier, $\left(\left(Q_{O} f_{O}\right) / B W\right)<0.1$ where $f_{0}$ and $B W$ are expressed in Hz . If source impedance varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

Figure 43. Multiple Feedback Bandpass Filter

TSOP-5
CASE 483
ISSUE N
DATE 12 AUG 2020
SCALE 2:1

NOTES

1. DIMENSIONING AND TOLERANCING PER ASME

Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH

THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD

FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION A.
5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

| DIM | MILLIMETERS |  |
| :---: | :---: | :---: |
|  | MIN | MAX |
| $\mathbf{A}$ | 2.85 | 3.15 |
| $\mathbf{B}$ | 1.35 | 1.65 |
| $\mathbf{C}$ | 0.90 | 1.10 |
| $\mathbf{D}$ | 0.25 | 0.50 |
| $\mathbf{G}$ | 0.95 | BSC |
| $\mathbf{H}$ | 0.01 | 0.10 |
| $\mathbf{J}$ | 0.10 | 0.26 |
| $\mathbf{K}$ | 0.20 | 0.60 |
| $\mathbf{M}$ | 0 | $10^{\circ}$ |
| $\mathbf{S}$ | 2.50 | 3.00 |

GENERIC MARKING DIAGRAM*

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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| DESCRIPTION: | TSOP-5 | PAGE 1 OF 1 |



SOIC-8 NB
CASE 751-07
ISSUE AK
SCALE 1:1
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
. CONTROLLING DIMENSION: MILLIMETER.
2. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
3. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
4. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
5. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

| DIM | MILLIMETERS |  | INCHES |  |
| :---: | :---: | :---: | :---: | :---: |
|  | MIN | MAX | MIN | MAX |
|  | 4.80 | 5.00 | 0.189 | 0.197 |
| B | 3.80 | 4.00 | 0.150 | 0.157 |
| C | 1.35 | 1.75 | 0.053 | 0.069 |
| D | 0.33 | 0.51 | 0.013 | 0.020 |
| G | 1.27 BSC |  | 0.050 BSC |  |
| H | 0.10 | 0.25 | 0.004 | 0.010 |
| J | 0.19 | 0.25 | 0.007 | 0.010 |
| K | 0.40 | 1.27 | 0.016 | 0.050 |
| M | 0 | $0^{\circ}$ | $8^{\circ}$ | 0 |
|  | $\circ$ | 8 |  |  |
| N | 0.25 | 0.50 | 0.010 | 0.020 |
| S | 5.80 | 6.20 | 0.228 | 0.244 |

GENERIC
MARKING DIAGRAM*



XXXXX = Specific Device Code
A = Assembly Location
L Wafer Lot
= Year
= Work Week
= Pb-Free Package
*This information is generic. Please refer to device data sheet for actual part marking. $\mathrm{Pb}-\mathrm{Free}$ indicator, " G " or microdot " $\mathrm{=}$ ", may or may not be present. Some products may not follow the Generic Marking.
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## STYLES ON PAGE 2

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| DESCRIPTION: | SOIC-8 NB | PAGE 1 OF 2 |

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SOIC-8 NB
CASE 751-07
ISSUE AK
DATE 16 FEB 2011

STYLE

| PIN 1. | EMITTER |
| ---: | :--- |
| 2. | COLLECTOR |
| 3. | COLLECTOR |
| 4. | EMITTER |
| 5. | EMITTER |
| 6. | BASE |
| 7. | BASE |
| 8. | EMITTER |
| STYLE 5: |  |
| PIN 1. | DRAIN |
| 2. | DRAIN |
| 3. | DRAIN |
| 4. | DRAIN |
| 5. | GATE |
| 6. | GATE |
| 7. | SOURCE |
| 8. | SOURCE |

STYLE 9:
PIN 1. EMITTER, COMMON
COLLECTOR, DIE \#1 COLLECTOR, DIE \#2 EMITTER, COMMON EMITTER, COMMON BASE, DIE \#2
BASE, DIE \#1
8. EMITTER, COMMON

STYLE 13:
PIN 1. N.C.
2. SOURCE
3. SOURCE

GATE
DRAIN
DRAIN
DRAIN
8. DRAIN

STYLE 17:
PIN 1. VCC
V2OUT
V10UT
V10UT
TXE
RXE
VEE
8. ACC

STYLE 21:
PIN 1. CATHODE 1
2. CATHODE 2
3. CATHODE 3

CATHODE 4
CATHODE 5
6. COMMON ANODE
7. COMMON ANODE
8. CATHODE 6

STYLE 25:
PIN 1. VIN
2. $N / C$

REXT
GND
IOUT
IOUT
IOUT
8. IOUT

## STYLE 29:

PIN 1. BASE, DIE \#
EMITTER, \#1
BASE, \#2
. EMITTER, \#2
5. COLLECTOR, \#2
6. COLLECTOR, \#2
7. COLLECTOR, \#1
7. COLLECTOR, \#1

STYLE
PIN 1. COLIECTOR, DIE,
2. COLLECTOR, \#1
3. COLLECTOR, \#2

COLLECTOR, \#2
BASE, \#2
. EMITTER, \#2
7. BASE, \#1
8. EMITTER, \#1

STYLE 6:
PIN 1. SOURCE
DRAIN
3. DRAIN
4. SOURCE

SOURCE
6. GATE
7. GATE
8. SOURCE

STYLE 10:
PIN 1. GROUND
2. BIAS 1
3. OUTPUT

GROUND
GROUND
BIAS 2
7. INPUT
8. GROUND

STYLE 14:
PIN 1. N-SOURCE
2. N-GATE

P-SOURCE
P-GATE
5-DRAIN
. P-DRAIN
7. N -DRAIN
8. N-DRAIN

STYLE 18
PIN 1. ANODE
2. ANODE
3. SOURCE
4. GATE
5. DRAIN
6. DRAIN
7. CATHODE
8. CATHODE

STYLE 22 :
PIN 1. I/O LINE
2. COMMON CATHODE/VCC
3. COMMON CATHODE/VCC
4. I/O LINE 3
5. COMMON ANODE/GND
6. I/O LINE 4
7. I/O LINE 5
8. COMMON ANODE/GND

STYLE 26:
PIN 1. GND
2. $\mathrm{dv} / \mathrm{dt}$
3. ENABLE
4. ILIMIT
5. SOURCE

SOURCE
7. SOURCE
8. VCC

STYLE 30:
PIN 1. DRAIN 1
2. DRAIN 1
. GATE 2
4. SOURCE 2
5. SOURCE 1/DRAIN 2
. SOURCE 1/DRAIN 2
SOURCE 1/DRAIN 2
8. GATE 1

STYLE 3
STYLE
N 1. DRAIN, DIE
2. DRAIN, \#1
3. DRAIN, \#2
4. DRAIN, \#2
5. GATE, \#2
7. GATE, \#1
8. SOURCE, \#1

## STYLE 7

PIN 1. INPUT
2. EXTERNAL BYPASS
3. THIRD STAGE SOURCE
4. GROUND
5. DRAIN
6. GATE 3
7. SECOND STAGE Vd
8. FIRST STAGE Vd

## STYLE 11:

PIN 1. SOURCE
2. GATE 1
3. SOURCE 2
4. GATE 2
5. DRAIN 2
6. DRAIN 2
7. DRAIN
8. DRAIN 1

## STYLE 15:

PIN 1. ANODE 1
2. ANODE 1
3. ANODE 1
4. ANODE 1
5. CATHODE, COMMON
6. CATHODE, COMMON
7. CATHODE, COMMON
8. CATHODE, COMMON

## STYLE 19:

PIN 1. SOURCE
2. GATE 1
3. SOURCE 2
4. GATE 2
5. DRAIN 2
6. MIRROR 2
7. DRAIN 1
8. MIRROR 1

## STYLE 23:

PIN 1. LINE 1 IN
2. COMMON ANODE/GND
3. COMMON ANODE/GND
4. LINE 2 IN
5. LINE 2 OUT
6. COMMON ANODE/GND
7. COMMON ANODE/GND
8. LINE 1 OUT

STYLE 27:
PIN 1. ILIMIT
2. OVLO
3. UVLO
4. INPUT+
5. INPUT+
5. SOURCE
6. SOURCE
7. SOURCE
8. DRAIN

STYLE 4:
PIN 1. ANODE
2. ANODE
3. ANODE
4. ANODE
5. ANODE
6. ANODE
8. COMMON CATHODE

## STYLE 8:

PIN 1. COLLECTOR, DIE \#1
2. BASE, \#1
3. BASE, \#2
4. COLLECTOR, \#2
5. COLLECTOR, \#2
6. EMITTER, \#2
7. EMITTER, \#1
8. COLLECTOR, \#1

## STYLE 12

PIN 1. SOURCE
2. SOURCE
3. SOURCE
4. GATE
5. DRAIN
6. DRAIN
7. DRAIN
8. DRAIN

## STYLE 16:

PIN 1. EMITTER, DIE \#1
2. BASE, DIE \#1
3. EMITTER, DIE \#2
3. EMITTER, DIE
4. BASE, DIE \#2
4. BASE, DIE \#2
6. COLLECTOR, DIE \#2
7. COLLECTOR, DIE \#1
8. COLLECTOR, DIE \#1

## STYLE 20:

PIN 1. SOURCE (N)
2. GATE (N)
3. SOURCE (P)
4. GATE (P)
5. DRAIN
6. DRAIN
7. DRAIN
8. DRAIN

## STYLE 24:

PIN 1. BASE
2. EMITTER
3. COLLECTOR/ANODE
4. COLLECTOR/ANODE
5. CATHODE
6. CATHODE
7. COLLECTOR/ANODE
8. COLLECTOR/ANODE

## STYLE 28:

PIN 1. SW_TO_GND
2. DASIC $\bar{O} F F$
3. DASIC_SW_DET
4. GND
5. V_MON
6. VBUULK
7. VBULK
8. VIN

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SOIC-14 NB
CASE 751A-03
ISSUE L
SCALE 1:1


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR

PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION
4. DIMENSIONS D AND E DO NOT INCLUDE

MOLD PROTRUSIONS.
5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

SIDE.

| DIM | MILLIMETERS |  | INCHES |  |
| :---: | :---: | :---: | :---: | :---: |
|  | MIN | MAX | MIN | MAX |
|  | 1.35 | 1.75 | 0.054 | 0.068 |
| A1 | 0.10 | 0.25 | 0.004 | 0.010 |
| A3 | 0.19 | 0.25 | 0.008 | 0.010 |
| b | 0.35 | 0.49 | 0.014 | 0.019 |
| D | 8.55 | 8.75 | 0.337 | 0.344 |
| E | 3.80 | 4.00 | 0.150 | 0.157 |
| e | 1.27 | BSC | 0.050 | BSC |
| H | 5.80 | 6.20 | 0.228 | 0.244 |
| h | 0.25 | 0.50 | 0.010 | 0.019 |
| L | 0.40 | 1.25 | 0.016 | 0.049 |
| M | $0^{\circ}$ | $7^{\circ}$ | $0^{\circ}$ | $7^{\circ}$ |



DIMENSIONS: MILLIMETERS
*For additional information on our $\mathrm{Pb}-$ Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## STYLES ON PAGE 2

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STYLE 1:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. NO CONNECTION
5. ANODE/CATHODE
6. NO CONNECTION
7. ANODE/CATHODE
8. ANODE/CATHODE
9. ANODE/CATHODE
10. NO CONNECTION
11. ANODE/CATHODE
12. ANODE/CATHODE
13. NO CONNECTION
4. COMMON ANODE
STYLE $5:$

PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHOD
4. ANODE/CATHOD
4. ANODE/CATHODE
5. ANODE/CATHODE
6. NO CONNECTION
7. COMMON ANODE
8. COMMON CATHOD
9. ANODE/CATHODE
10. ANODE/CATHODE
11. ANODE/CATHODE
12. ANODE/CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 2 :
CANCELLED

STYLE 3:
PIN 1. NO CONNECTION 2. ANODE 3. ANODE
4. NO CONNECTION 5. ANODE
6. NO CONNECTION
7. ANODE
8. ANODE
9. ANODE
10. NO CONNECTION
11. ANODE
12. ANODE
13. NO CONNECTION
14. COMMON CATHODE

## STYLE 6

PIN 1. CATHODE
2. CATHODE
3. CATHODE
4. CATHODE
5. CATHODE
5. CATHODE
6. CATHODE
7. CATHOD
8. ANODE
9. ANODE
10. ANODE
11. ANODE
12. ANODE
13. ANODE
14. ANODE

STYLE 7:
PIN 1. ANODE/CATHODE
2. COMMON ANODE
3. COMMON CATHODE
4. ANODE/CATHODE
5. ANODE/CATHODE
6. ANODE/CATHODE
7. ANODE/CATHODE
8. ANODE/CATHODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. COMMON CATHODE

1. COMMON CATHODE
2. COMMON ANODE
3. ANODE/CATHODE

STYLE 4:
PIN 1. NO CONNECTION 2. CATHODE
3. CATHODE
4. NO CONNECTION
5. CATHODE
6. NO CONNECTION
7. CATHODE
. CATHODE
9. CATHODE
10. NO CONNECTION
11. CATHODE
12. CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 8:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. NO CONNECTION
4. NO CONNECTION
5. ANODE/CATHODE
6. ANODE/CATHODE
7. COMMON ANODE
8. COMMON ANODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. NO CONNECTION
11. NO CONNECTION
12. ANODE/CATHODE
12. ANODE/CATHODE
13. ANODE/CATHODE
14. COMMON CATHODE

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Micro8
CASE 846A-02
ISSUE K
DATE 16 JUL 2020
SCALE 2:1

## NDTES:

1. DIMENSIDNING AND TZLERANCING PER ASME Y14.5M, 2009.
2. CINTRZLLING DIMENSIDN: MILLIMETERS
3. DIMENSIUN b DUES NDT INCLUDE DAMBAR PRDTRUSIDN ALLIWABLE PRITRUSIDN SHALL BE 0.10 mm IN EXCESS DF MAXIMUM MATERIAL CINDITIDN
4. DIMENSIUNS D AND E DD NDT INCLUDE MLLD FLASH, PRDTRUSIDr GR GATE BURRS, MILD FLASH, PRDTRUSIUNS, $G R$ GATE BURRS SHALL NDT EXCEED 0.15 mm PER SIDE. DIMENSIDN E DDES NDT INCLUDE INTERLEAD FLASH $\square R$ PRITRUSIDN. INTERLEAD FLASH IR PRZTRUSIDN SHALL NDT EXCEED 0.25 mm PER SIDE. DIMENSIINS D AND E ARE DETERMINED AT DATUM F.
5. DATUMS A AND B ARE TV BE DETERMINED AT DATUM F
6. A1 IS DEFINED AS THE VERTICAL DISTANCE FRIM THE SEATING PLANE TI THE LIWEST PDINT IN THE PACKAGE BGDY.
GENERIC MARKING DIAGRAM*

= Specific Device Code
$\begin{array}{ll}\text { XXXX } & =\text { Specific Device Code } \\ \text { A } & =\text { Assembly Location }\end{array}$
Y = Year
W = Work Week

- = Pb-Free Package


END VIEW
0.65

PITCH ${ }^{-}$
RECDMMENDED MDUNTING FIDTPRINT

| DIM | MILLIMETERS |  |  |
| :---: | :---: | :---: | :---: |
|  | MIN. | NIM. | MAX. |
| A | --- | -- | 1.10 |
| A1 | 0.05 | 0.08 | 0.15 |
| b | 0.25 | 0.33 | 0.40 |
| C | 0.13 | 0.18 | 0.23 |
| D | 2.90 | 3.00 | 3.10 |
| E | 2.90 | 3.00 | 3.10 |
| e | 0.65 BSC |  |  |
| $\mathrm{H}_{\mathrm{E}}$ | 4.75 | 4.90 |  |
| L | 0.40 | 5.05 |  |



PITCH
STYLE 1:
PIN 1. SOURCE
2. SOURCE
3. SOURCE
4. GATE
5. DRAIN
6. DRAIN
7. DRAIN
8. DRAIN

## STYLE 2:

PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2 4. GATE 2 5. DRAIN 2 6. DRAIN 2 7. DRAIN 1

## STYLE 3:

PIN 1. N-SOURCE 2. N-GATE 3. P-SOURCE
4. P-GATE
4. P-GATE
5. P-DRAIN
6. P-DRAIN
7. N-DRAIN
8. N -DRAIN or may not be present. Some products may not follow the Generic Marking

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TSSOP-14 WB
CASE 948G
ISSUE C
DATE 17 FEB 2016


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS MOLD FLASH OR GATE BURRS SHALL NOT MOLD FLASH OR GATE BURRS
4. DIMENSION B DOES NOT INCLUDE

INTERLEAD FLASH OR PROTRUSION.
INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR
PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

| DIM | MILLIMETERS |  | INCHES |  |
| :---: | :---: | :---: | :---: | :---: |
|  | MIN | MAX | MIN | MAX |
| A | 4.90 | 5.10 | 0.193 | 0.200 |
| B | 4.30 | 4.50 | 0.169 | 0.177 |
| C | --- | 1.20 | --- | 0.047 |
| D | 0.05 | 0.15 | 0.002 | 0.006 |
| F | 0.50 | 0.75 | 0.020 | 0.030 |
| G | 0.65 | BSC | 0.026 |  |
| BSC |  |  |  |  |
| H | 0.50 | 0.60 | 0.020 | 0.024 |
| J | 0.09 | 0.20 | 0.004 | 0.008 |
| J1 | 0.09 | 0.16 | 0.004 | 0.006 |
| K | 0.19 | 0.30 | 0.007 | 0.012 |
| K1 | 0.19 | 0.25 | 0.007 | 0.010 |
| L | 6.40 BSC | 0.252 | BSC |  |
| M | $00^{\circ}$ | $8^{\circ}$ | $0^{\circ}$ | $8^{\circ}$ |

GENERIC MARKING DIAGRAM*

SOLDERING FOOTPRINT


|  |
| :---: |
|  |  |
|  |  |
|  |  |
|  |  |
|  |  |


| A | $=$ Assembly Location |
| :--- | :--- |
| L | $=$ Wafer Lot |
| Y | $=$ Year |
| W | $=$ Work Week |
| - | $=$ Pb-Free Package |

(Note: Microdot may be in either location)
*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

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